SKFM1040CW-D-Q1 Thru SKFM10200CW-D-Q1

List

SKFM1040CW-D-Q1 Thru SKFM10200CW-D-Q1

10.0Amp Surface Mount Schottky Barrier Rectifiers : 40 ~ 200V

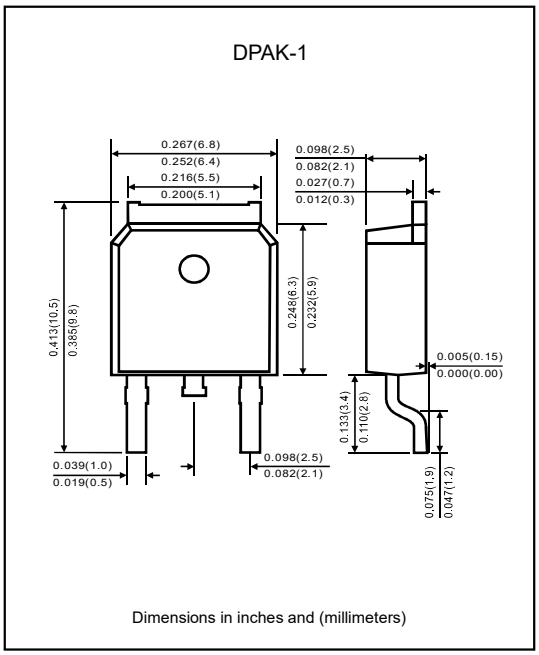
Features

- Construction utilizes void-free molded plastic technique.
- Low reverse leakage.
- High forward surge current capability.
- High temperature soldering guaranteed 260ºC/10 seconds at terminals.
- Qualified to AEC-Q101 standards for high reliability.
- Lead-free parts meet RoHS requirement.
- Suffix "-H" indicates Halogen free parts, ex.SKFM1040CW-D-Q1-H.

Mechanical data

- Epoxy:UL94-V0 rated flame retardant.
- Case : Molded plastic, DPAK-1 (TO-252).
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026.
- Polarity : Indicated by cathode band.
- Mounting Position : Any.

Package outline



Maximum ratings and electrical characteristics (At T_A=25°C unless otherwise noted)

Parameter	Symbol	SKFM1040 CW-D-Q1	SKFM1045 CW-D-Q1	SKFM1060 CW-D-Q1	SKFM10100 CW-D-Q1	SKFM10150 CW-D-Q1	SKFM10200 CW-D-Q1	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	40	45	60	100	150	200	V
Maximum RMS voltage	V_{RMS}	28	31.5	42	70	105	140	V
Maximum DC blocking voltage	V_{DC}	40	45	60	100	150	200	V
Maximum average forward rectified (Per device)	$I_{(AV)}$	10						A
Current at T_C=110ºC (Per diode)		5						
Peak forward surge current 8.3ms single half sine wave superimposed on rated load (JEDEC Method)	I_{FSM}	120						A
Maximum instantaneous forward voltage per diode at 5.0A	V_F	0.55		0.75	0.85	0.95		V
Maximum DC reverse current (T_A=25ºC)	I_R	0.5			0.05			mA
At rated DC blocking voltage (T_A=125ºC)		50			10			
Typical thermal resistance	$R_{\theta JC}$	2.5						ºC/W
Operating junction temperature range	T_J	-55 to +150			-55 to +175			ºC
Storage temperature range	T_{STG}	-55 to +150						ºC

Note : 1. Single phase half-wave 60Hz, resistive of inductive load, for capacitive load current derate by 20%.

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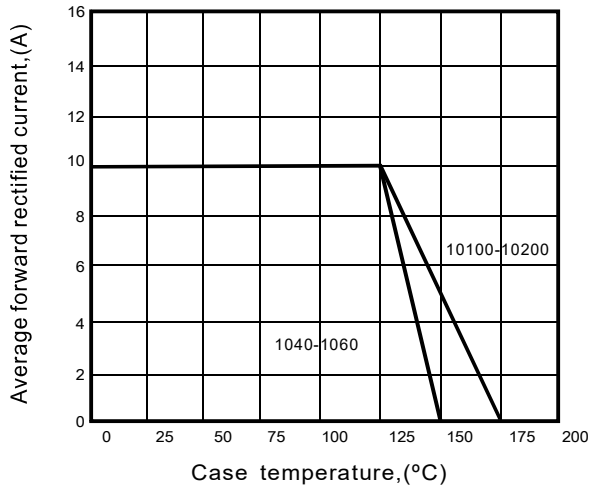
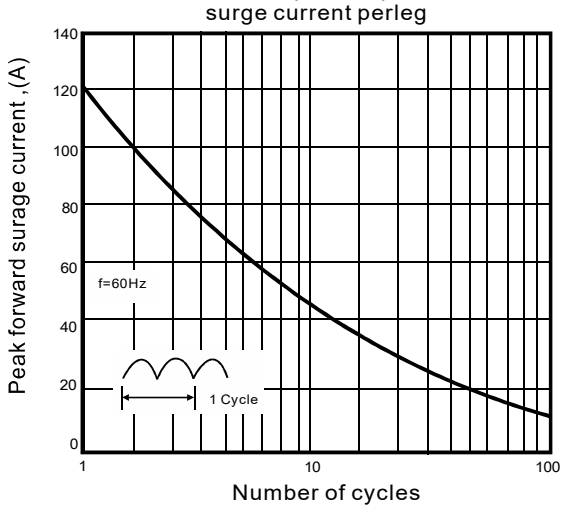
Rating and characteristic curves

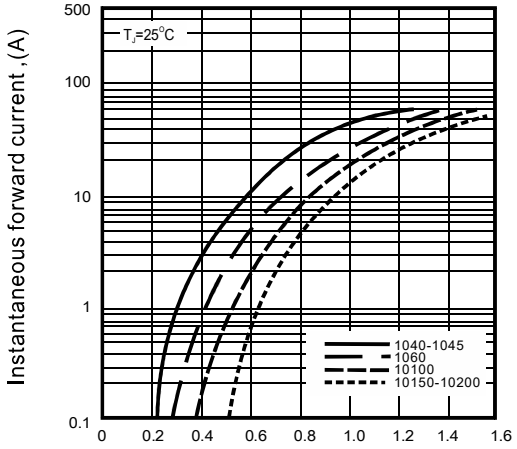
Derating curve output rectified current



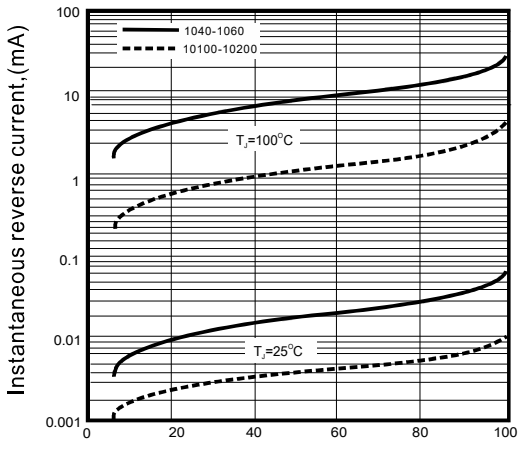
Maximum non-repetitive peak forward surge current perleg



Typical forward voltage characteristics



Typical reverse leakage characteristics



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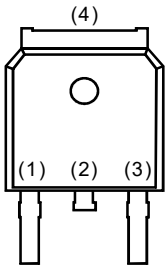
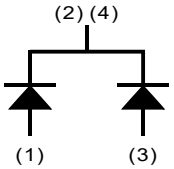
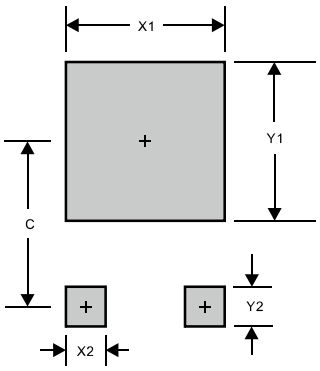
Pinning information

Pin	Simplified outline	Symbol
Pin1, 3 Anode Pin2, 4 Cathode		

Marking

Type number	Marking code
SKFM1040CW-D-Q1	MBR1040CSV
SKFM1045CW-D-Q1	MBR1045CSV
SKFM1060CW-D-Q1	MBR1060CSV
SKFM10100CW-D-Q1	MBR10100CSV
SKFM10150CW-D-Q1	MBR10150CSV
SKFM10200CW-D-Q1	MBR10200CSV

Suggested solder pad layout



Package	DPAK-1
C	0.261(6.64)
X1	0.240(6.10)
Y1	0.298(7.57)
X2	0.056(1.42)
Y2	0.109(2.76)

Dimensions in inches and (millimeters)

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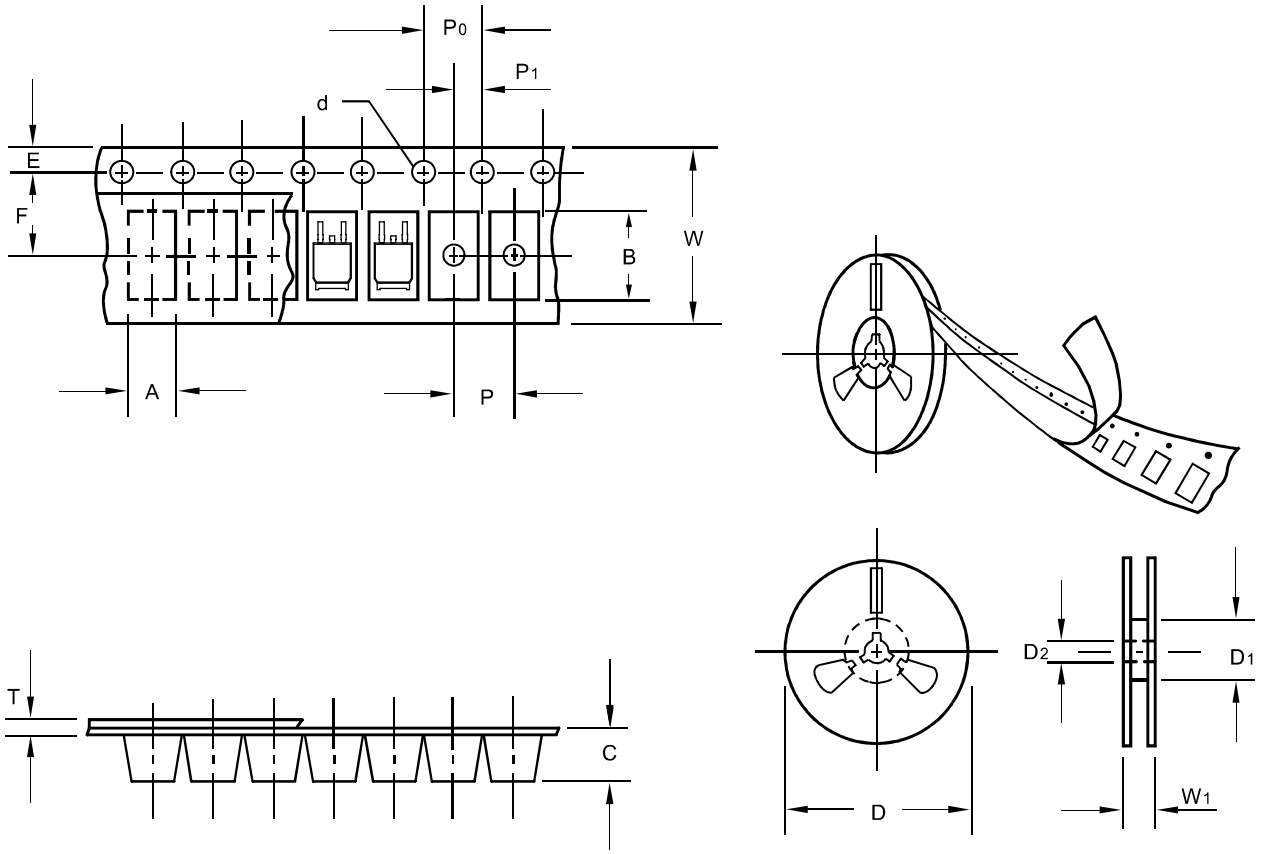
Packing information



unit:mm

Item	Symbol	Tolerance	DPAK-1
Carrier width	A	0.1	6.90
Carrier length	B	0.1	10.50
Carrier depth	C	0.1	2.70
Sprocket hole	d	0.1	1.55
13" Reel outside diameter	D	2.0	330.00
13" Reel inner diameter	D_1	min	50.00
7" Reel outside diameter	D	2.0	-
7" Reel inner diameter	D_1	min	-
Feed hole diameter	D_2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	7.50
Punch hole pitch	P	0.1	8.00
Sprocket hole pitch	P_0	0.1	4.00
Embossment center	P_1	0.1	2.00
Overall tape thickness	T	0.1	0.30
Tape width	W	0.3	16.00
Reel width	W_1	1.0	22.00

Note:Devices are packed in accor dance with EIA standar RS-481-A and specifications listed above.

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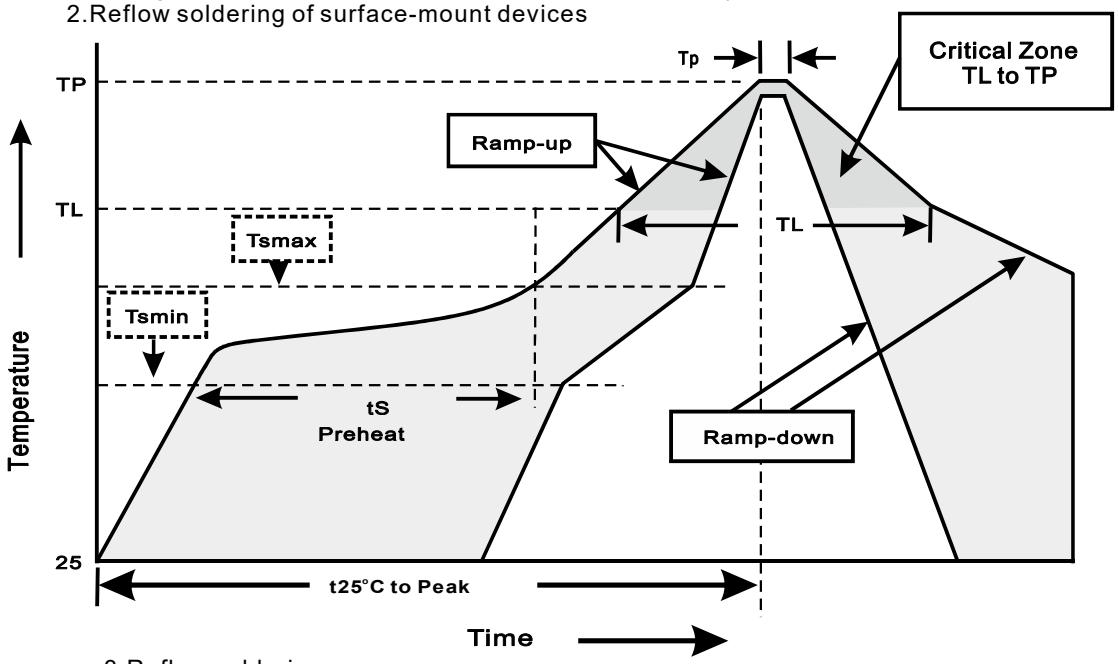
Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
DPAK-1 (TO-252)	13"	2,500	8.0	5,000	335*335*38	330	350*350*225	40,000	15.0

Suggested thermal profiles for soldering processes

1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
2.Reflow soldering of surface-mount devices



3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(T_L to T_P)	<3°C/sec
Preheat -Temperature Min(Tsmin) -Temperature Max(Tsmax) -Time(min to max)(t_s)	 150°C 200°C 60~120sec
Tsmax to T_L -Ramp-upRate	 <3°C/sec
Time maintained above: -Temperature(T_L) -Time(t_L)	 217°C 60~260sec
Peak Temperature(T_P)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t_P)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes

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High reliability test capabilities

Item Test	Conditions	Reference
1. Solder Resistance	at 260±5°C for 10±2sec. immerse body into solder 1/16"±1/32"	MIL-STD-750D METHOD-2031
2. Solderability	at 245±5°C for 5 sec.	MIL-STD-202F METHOD-208
3. High Temperature Reverse Bias	V_R=80% rate at T_J=125°C for 168 hrs.	MIL-STD-750D METHOD-1038
4. Forward Operation Life	Rated average rectifier current at T_A=25°C for 500hrs.	MIL-STD-750D METHOD-1027
5. Intermittent Operation Life	T_A = 25°C, I_F = I_O On state: power on for 5 min. off state: power off for 5 min. on and off for 500 cycles.	MIL-STD-750D METHOD-1036
6. Pressure Cooker	15P_{SIG} at T_A=121°C for 4 hrs.	JESD22-A102
7. Temperature Cycling	-55°C to +125°C dwelled for 30 min. and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
8. Forward Surge	8.3ms single half sine-wave , one surge.	MIL-STD-750D METHOD-4066-2
9. Humidity	at T_A=85°C, RH=85% for 1000hrs.	MIL-STD-750D METHOD-1021
10. High Temperature Storage Life	at 150°C for 1000 hrs.	MIL-STD-750D METHOD-1031